

Actilab Kick-off meeting

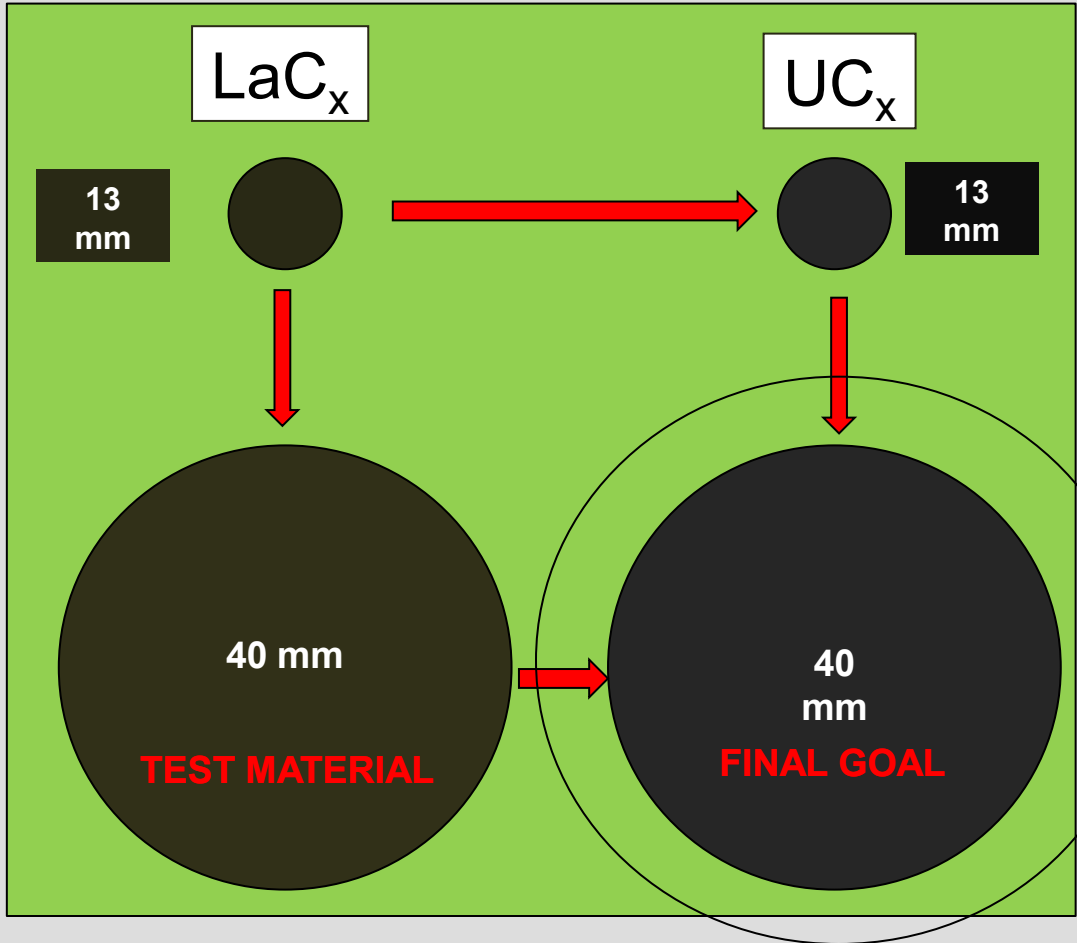
2010 SPES Target developments

Jacobo Montano

On behalf of the INFN-LNL

The Material R&D (Two labs are involved!)

R&D Started on 2004 ; LaC_x test material \rightarrow UC_x



Good News (!) concerning:

- 40 mm dia UC_x production
- UC_x on line test @ HRIBF
- Data analysis almost completed
- Start production of B_4C

Proton-rich beams for SPES- α

1 H																	2 He
3 Li	4 Be											5 B	6 C	7 N	8 O	9 F	10 Ne
11 Na	12 Mg											13 Al	14 Si	15 P	16 S	17 Cl	18 Ar
19 K	20 Ca	21 Sc	22 Ti	23 V	24 Cr	25 Mn	26 Fe	27 Co	28 Ni	29 Cu	30 Zn	31 Ga	32 Ge	33 As	34 Se	35 Br	36 Kr
37 Rb	38 Sr	39 Y	40 Zr	41 Nb	42 Mo	43 Tc	44 Ru	45 Rh	46 Pd	47 Ag	48 Cd	49 In	50 Sn	51 Sb	52 Te	53 I	54 Xe
55 Cs	56 Ba																
		72 Hf	73 Ta	74 W	75 Re	76 Os	77 Ir	78 Pt	79 Au	80 Hg	81 Tl	82 Pb	83 Bi	84 Po	85 At	86 Rn	
87 Fr	88 Ra																

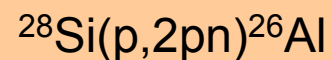
- Alkaline - Alkaline earth metals
- Post-transition elements
- Halogens
- Noble gases
- Transition metals

Lanthanides

57 La	58 Ce	59 Pr	60 Nd	61 Pm	62 Sm	63 Eu	64 Gd	65 Te	66 Dy	67 Ho	68 Er	69 Tm	70 Yb	71 Lu
89 Ac	90 Th	91 Pa	92 U	93 Np	94 Pu	95 Am	96 Cm	97 Bk	98 Cf	99 Es	100 Fm	101 Md	102 No	103 Lr

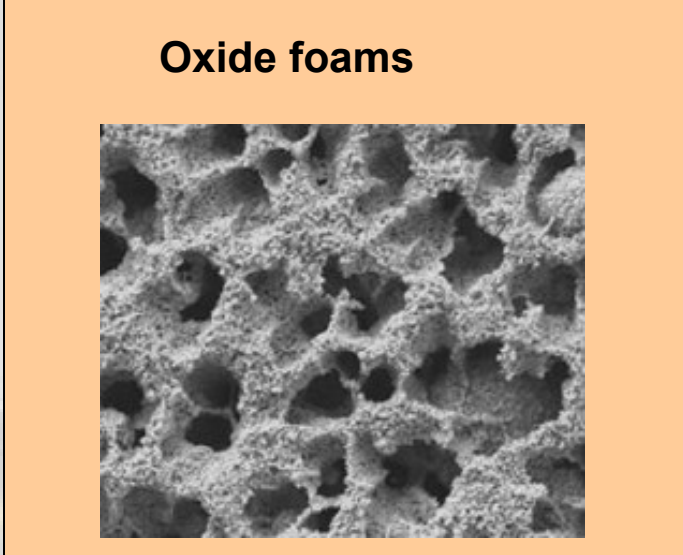
Elemento	A	Half Life	Target dedicati	Ionizzazione
Na	21	22.48 s	Al ₂ O ₃ – SiC - CeS	SIS
Na	22	2.6 a	Al ₂ O ₃ – SiC - CeS	SIS
Mg	22	3.86 s	Al ₂ O ₃ – SiC - CeS	LIS-FEBIAD
Mg	23	11.3 s	Al ₂ O ₃ – SiC - CeS	LIS-FEBIAD
Al	24	2.05 s	SiC - CeS	SIS-LIS
Al	25	7.18 s	SiC - CeS	SIS-LIS
Al	26	6.35 s	SiC - CeS	SIS-LIS
P	29	4.1 s	SiC - CeS	FEBIAD

SiC (Saint Gobain)



Oxide/Boron Carbide Target

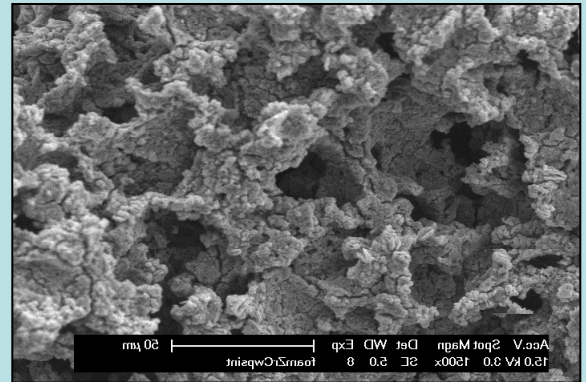
Elemento	A	Half Life	Target dedicati	Ionizzazione
Be	7	53.29 d	B ₄ C - Ossidi	LIS-FEBIAD
F	17	64.8 s	ZrO ₂ - HfO ₂	FEBIAD
F	18	109.7 m	Al ₂ O ₃	FEBIAD
Si	26	2.21 s	Al ₂ O ₃ - CeS	FEBIAD
Si	27	4.16 s	Al ₂ O ₃ - CeS	FEBIAD



Zr-based target

Elemento	A	Half Life	Target dedicati	Ionizzazione
As	73	80.3 d	ZrC – ZrO ₂	FEBIAD
As	74	17.77 d	ZrC – ZrO ₂	FEBIAD
Br	77	57 h	ZrC – ZrO ₂	FEBIAD
Br	78	6.46 m	ZrC – ZrO ₂	FEBIAD
Kr	79	34.9 h	ZrC – ZrO ₂	FEBIAD
Rb	80	30 s	ZrC – ZrO ₂	SIS
Rb	81	4.58 h	ZrC – ZrO ₂	SIS
Rb	82	6.3 h	ZrC – ZrO ₂	SIS
Rb	83	86.2 d	ZrC – ZrO ₂	SIS
Rb	84	32.8 d	ZrC – ZrO ₂	SIS
Sr	82	25.34 d	ZrC – ZrO ₂	SIS
Sr	83	32.4 h	ZrC – ZrO ₂	SIS
Sr	85	64.9 d	ZrC – ZrO ₂	SIS

ZrC foam

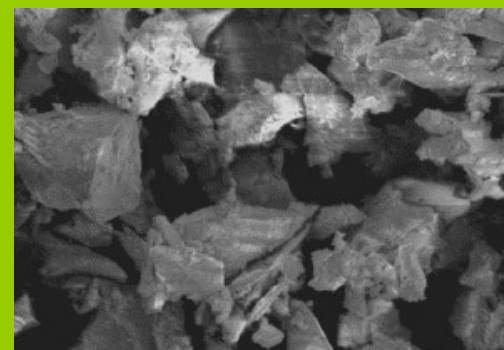


Elemento	A	Half Life	Target dedicati	Ionizzazione
I	126	13.11d	LaCx - CeS	FEBIAD
Xe	127	36.4 d	CeS	FEBIAD
Cs	129	32 h	CeS	SIS
Cs	130	29.2 m	LaCx - CeS	SIS
Cs	131	9.69 d	LaCx - CeS	SIS
Cs	132	6.47 d	LaCx - CeS	SIS
Ba	131	11.5 d	LaCx - CeS	SIS
La	133	3.91 h	CeS	SIS
La	134	6.67 m	CeS	SIS
La	135	19.4 h	CeS	SIS
La	136	9.9 m	CeS	SIS
Ce	135	17.76 h	LaCx	SIS
Pr	137	76.6 m	CeS	SIS
Pr	138	2 h	CeS	SIS
Pr	139	4.5 h	CeS	SIS
Pr	140	3.4 m	CeS	SIS

LaCx



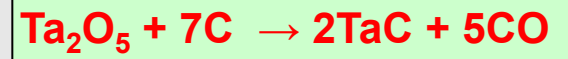
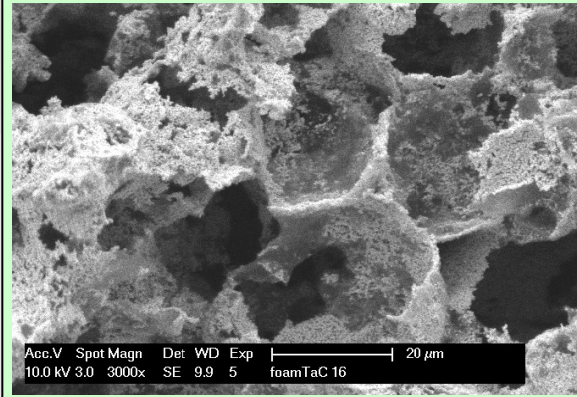
CeS



TaC target

Elemento	A	Half Life	Target dedicati	Ionizzazione
Ho	164	29 m	TaC	SIS
Tm	168	93.1 d	TaC	SIS
Yb	169	32 d	TaC	SIS
Lu	172	6.7 d	TaC	SIS
Lu	173	1.37 a	TaC	SIS
Lu	174	3.31 a	TaC	SIS
Hf	173	23.6 h	TaC	FEBIAD

TaC foam



Boron carbide (B_4C)

Sol-gel synthesis: boric acid $B(OH)_3$ + citric acid $C_6H_8O_7$



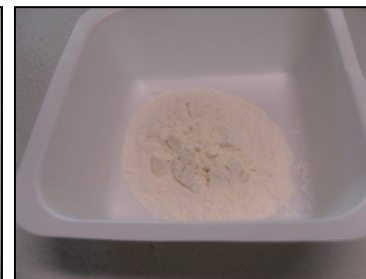
Solution of the acid



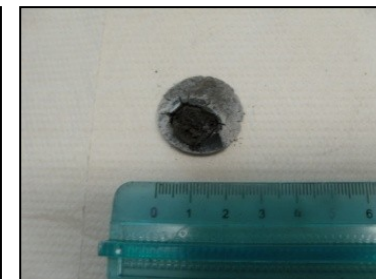
Gel formation



Dried gel



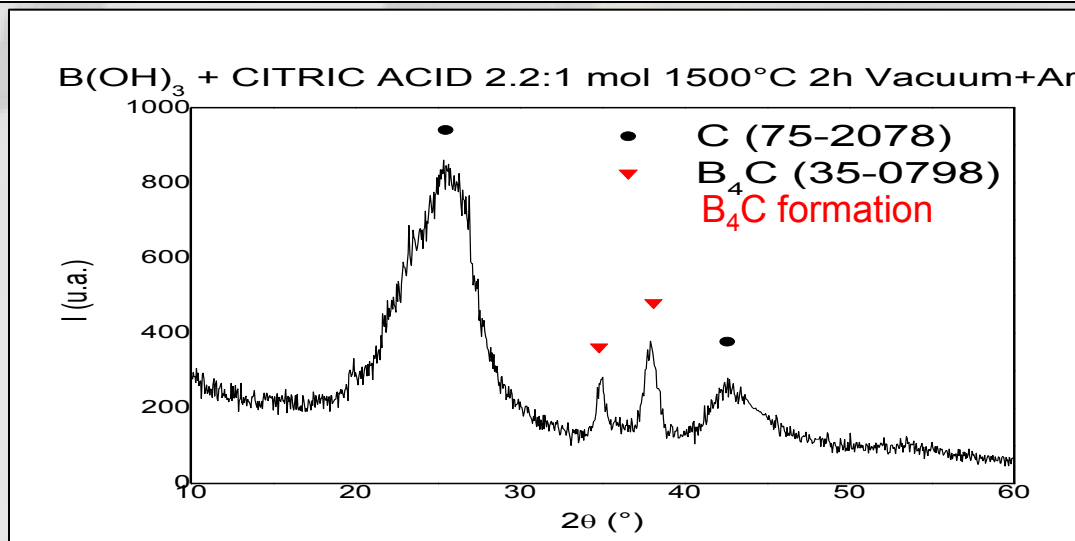
Grinding and
cold pressing



Thermal treated
sample

Thermal treatment :

- up to 800°C in low vacuum ($5 \cdot 10^{-2}$ mbar), $0.5^\circ\text{C}/\text{min}$
- up to 1500°C in vacuum with Ar flow ($5 \cdot 10^{-1}$ mbar), $3^\circ\text{C}/\text{min}$
- 2 hours at 1500°C

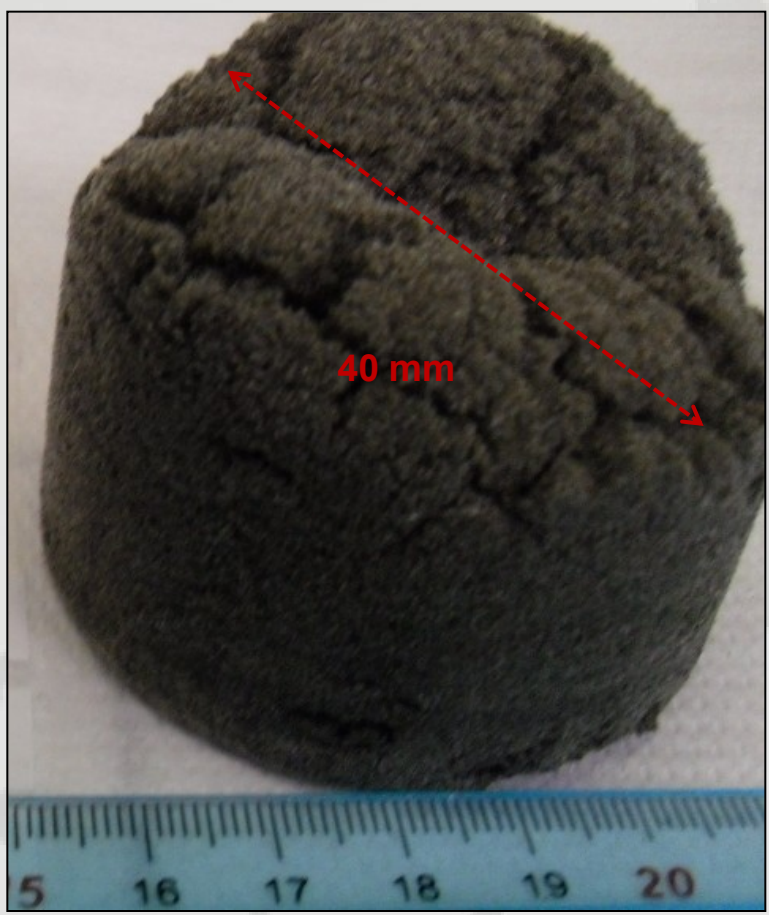


Further treatments:

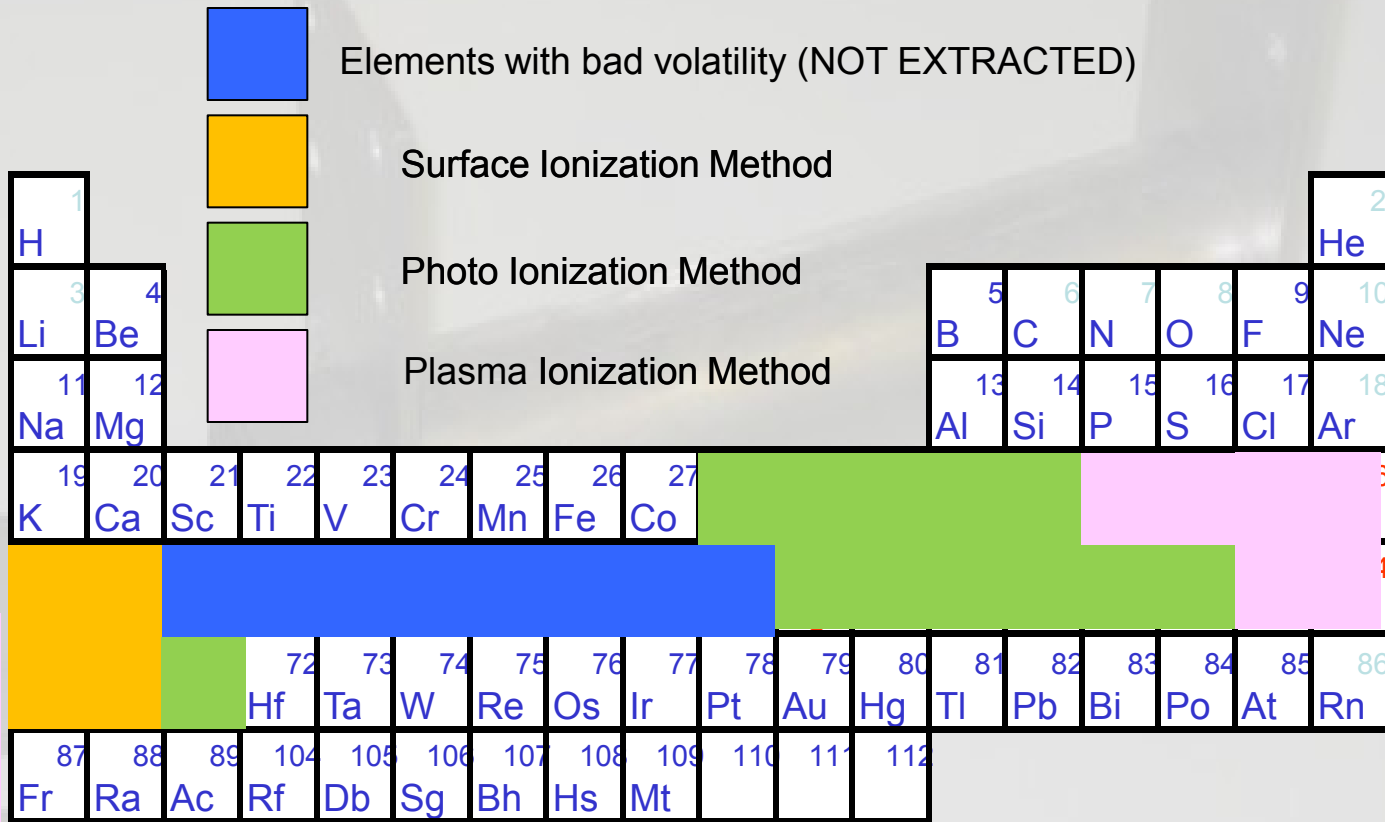
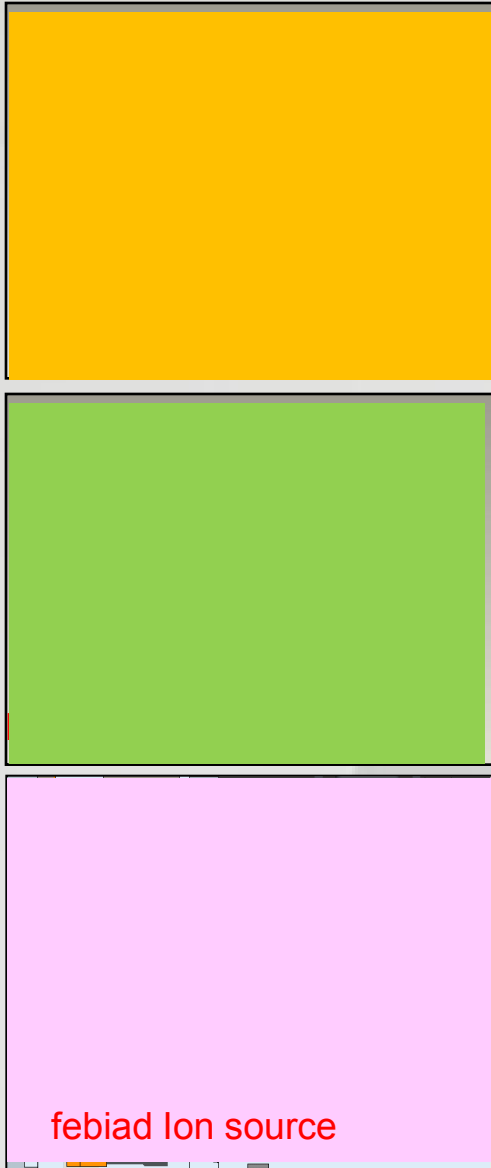
- Different boric acid/citric acid ratios
- Different time/temperatures
- Different pressures during treatment
- Use of binders

New Graphite disks

Graphite foams with different porosity
(for effusion tests)



Main n-rich SPES beams



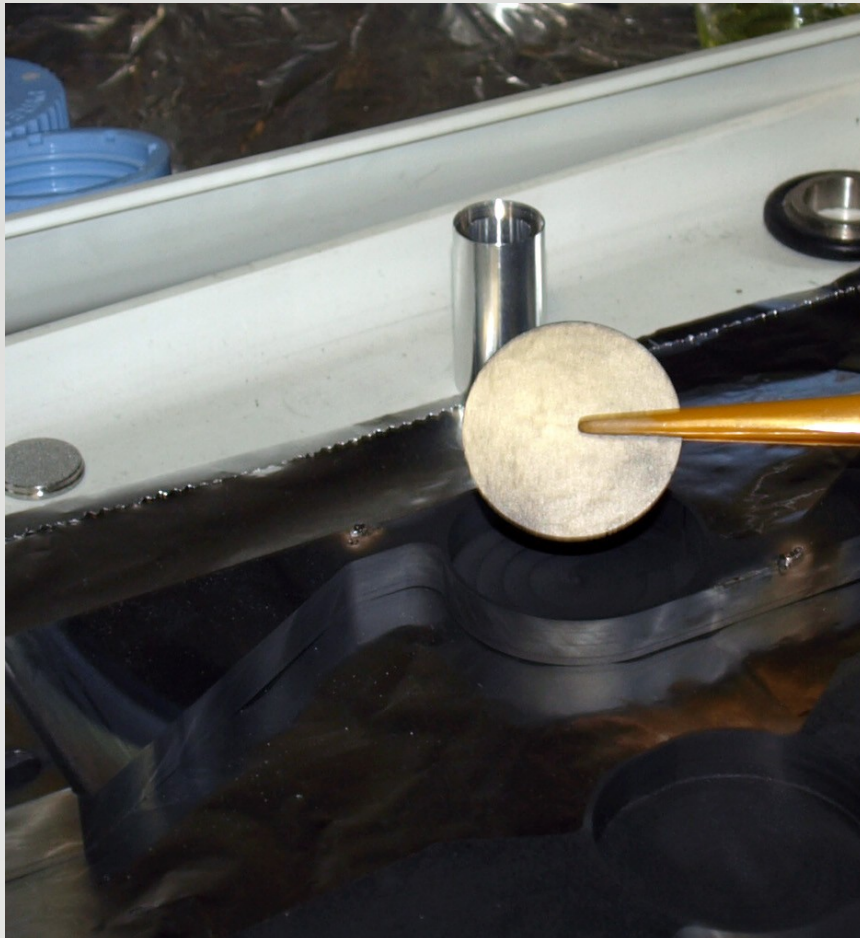
Main fission ²³⁸U fragments

Element	Mass	Most Intense isotope (1/s)	Ioniz. Eff (%)	Target	Ionization method	R&D (difficulty)
Ni	65-69	10^{+6}	6	UCx	LIS	**
Cu	66-76	10^{+6}	7	UCx	LIS	**
Zn	72-79	10^{+6}	5	UCx	LIS	**
Ga	72-84	10^{+6}	20	UCx	LIS	**
Ge	75-84	10^{+7}	3	UCx	LIS	***
Kr	85-93	10^{+7}	30	UCx	FEBIAD	***
Rb	86-94	10^{+9}	65	UCx	SIS	*
Sr	89-96	10^{+8}		UCx	SIS+LIS	***
Y	90-97	10^{+7}		UCx	LIS	****
Pd	111-118	10^{+7}		UCx	LIS	****
Ag	110-120	10^{+8}	14	UCx	LIS	**
Cd	115-124	10^{+8}	10	UCx	LIS	**
In	116-128	10^{+8}	15	UCx	SIS+LIS	**
Sn	123-134	10^{+9}	15	UCx	LIS	**
Sb	124-135	10^{+8}	3	UCx	LIS	***
Te	129-138	10^{+7}		UCx	LIS	****
Xe	137-142	10^{+7}	30	UCx	FEBIAD	***
Cs	134-144	10^{+9}	85	UCx	SIS	*
Ba	139-146	10^{+8}		UCx	SIS+LIS	***
La	141-145	10^{+6}		UCx	SIS+LIS	***

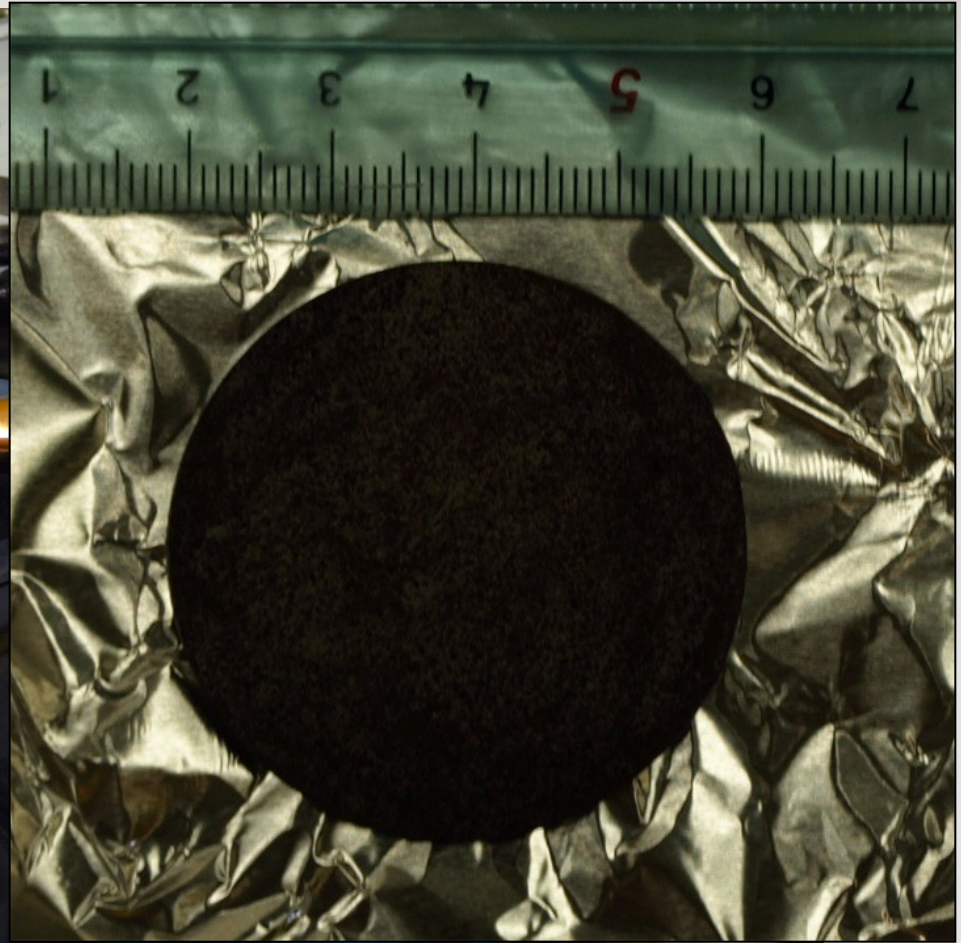
FIRST UCx 40mm. Pellet

Made at Padova UCx Lab (Feb '10)

Before thermal treatment



After thermal treatment

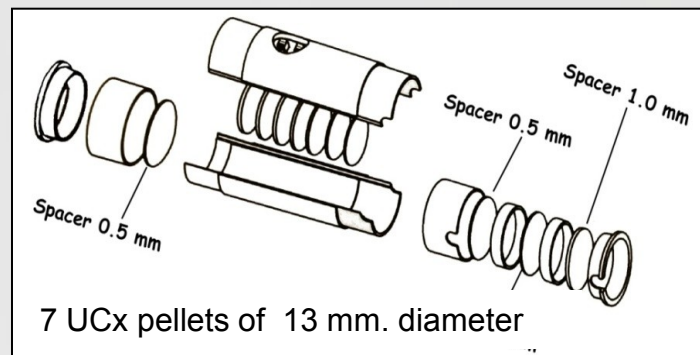


Thanks to Dan Stracener and ORNL-TIS group

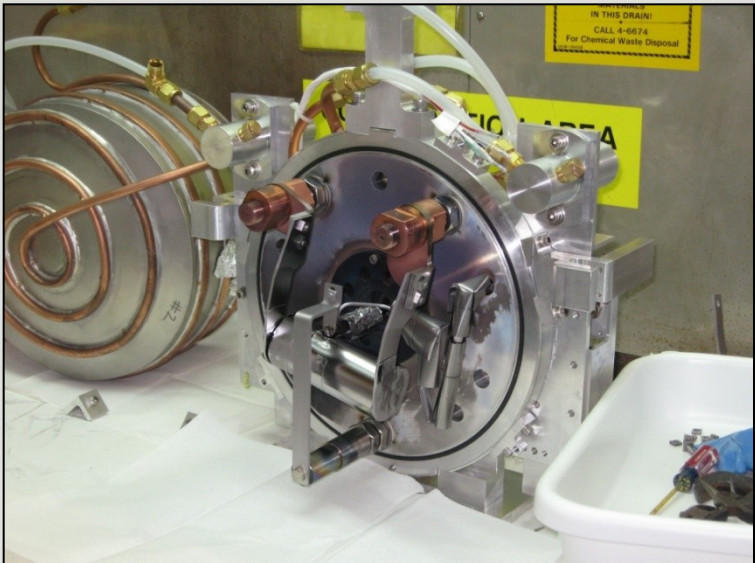
- Seven UC₂ samples SPES Target Group (in collaboration with HRIBF)
- Densities in the range of 4.2 g/cm³
- Used the SPES design where the targets are spaced out to allow for enhanced radiation to the walls of the container
- Heated to 2000° C for about two weeks without any out-gassing or obvious change in structure (samples observed after the on-line test)



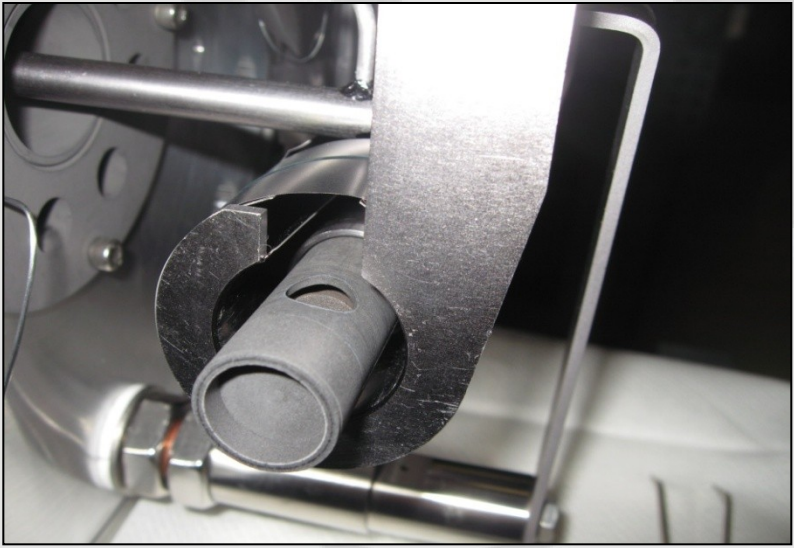
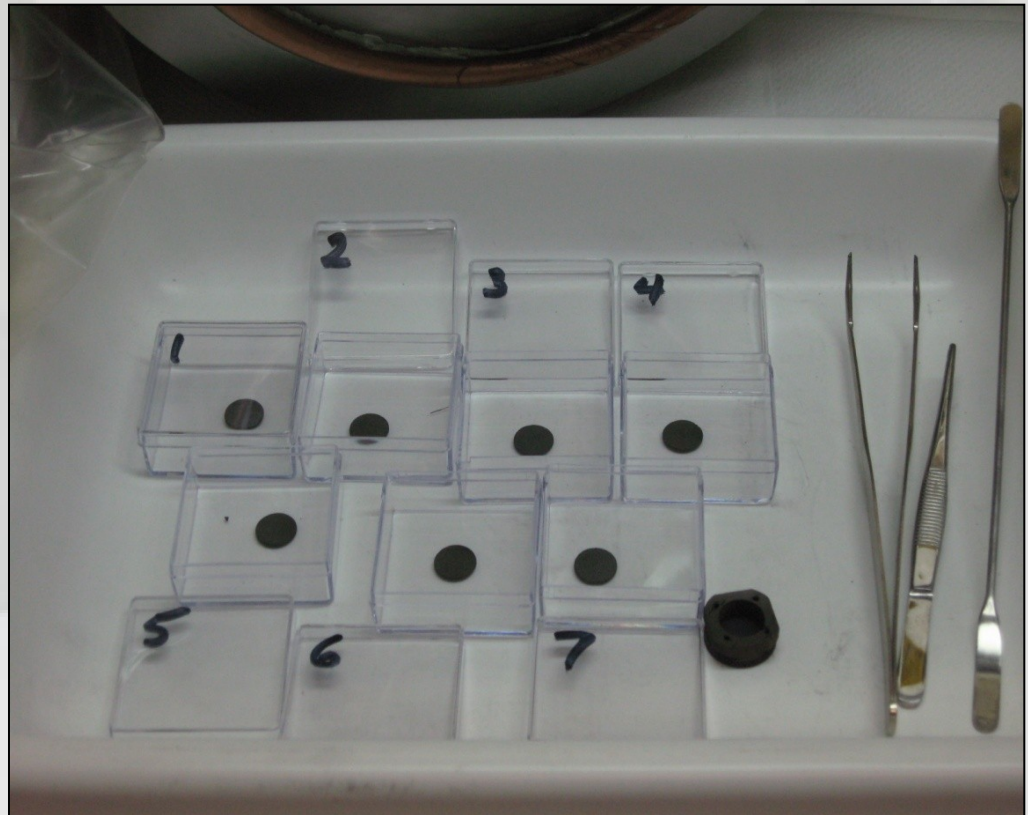
Actilab Kick-off meeting



SPES Target Group



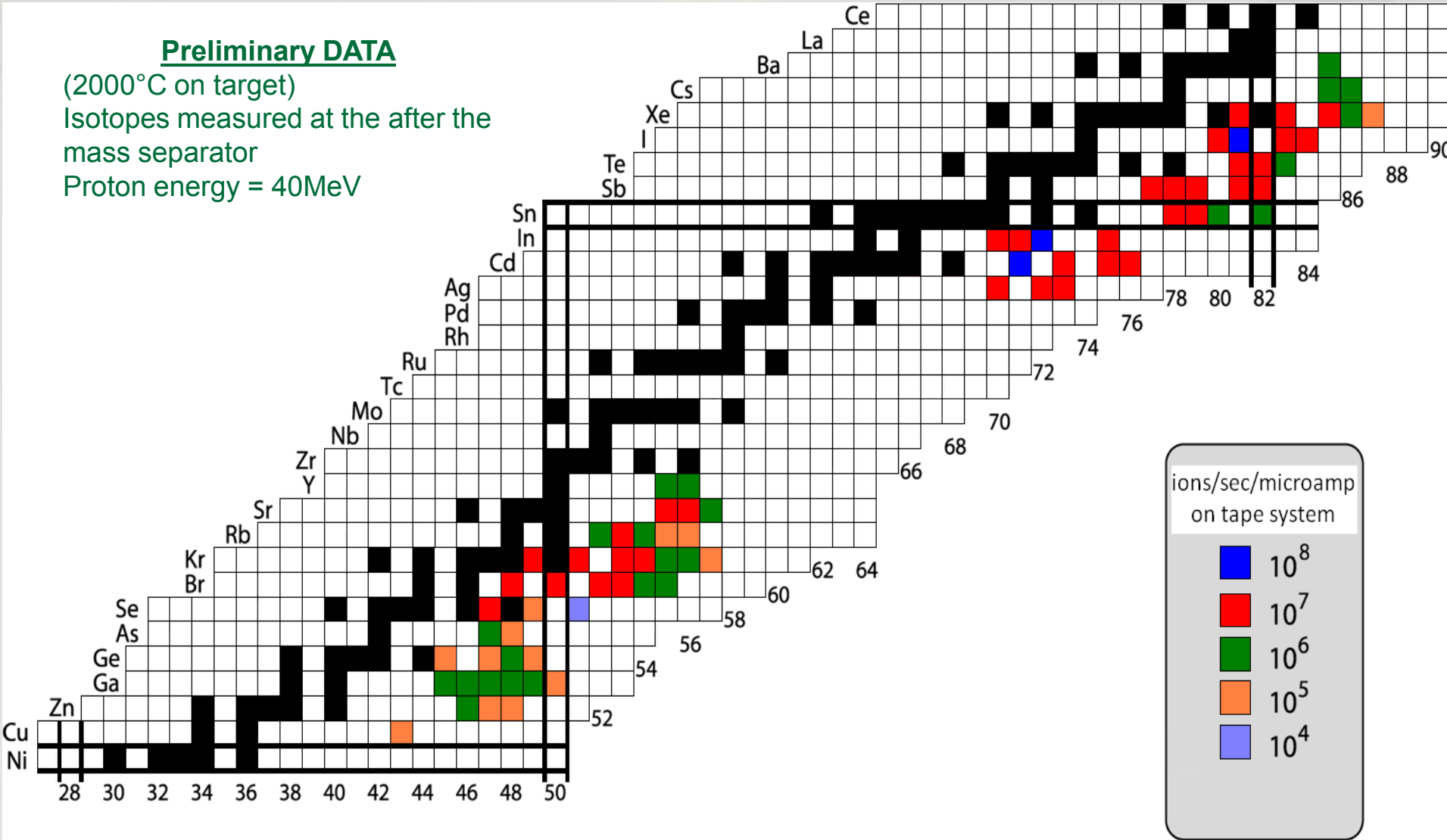
Target discs status after (6 days) 40 MeV irradiation



N-Rich Isotopes yields

Preliminary DATA

(2000°C on target)
 Isotopes measured at the after the mass separator
 Proton energy = 40MeV



ENSAR – ACTILAB: European contract signed but up to now we do not have green light to go on for fellowship application.

INFN involved in two sub-tasks:

- 1) Production
- 2) Characterization

INFN contribution to ACTILAB:

- 1) development of UCx with CNT in collaboration with CERN
two complete targets already available at ISOLDE.
- 2) we have new materials to be characterized and we are interested to collaborate at porosimetry measurements with Orsay.

2011 is a critical year for us about the material development. The Padova Laboratory is closing and we started the developing of a class A laboratory at LNL devoted to UCx development